Precision Monolithics Inc.

FEATURES

- On-Chip Latches For Both DACs
- +5V To +15V Single Supply Operation
- DACs Matched To 1%
- Four-Quadrant Multiplication
- TTL/CMOS Compatible
- 8-Bit Endpoint Linearity (±1/2 LSB)
- Full Temperature Operation
- Low Power Consumption
- Microprocessor Compatible
- Improved ESD Resistance
- Automatically Insertable Cerdip and Plastic Packages
- Available in Surface Mount SO, PLCC and LCC Packages

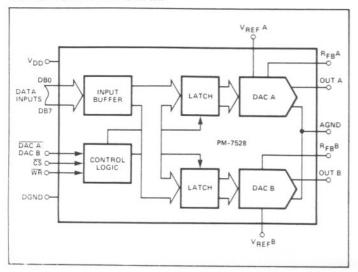
APPLICATIONS

- Digital Gain/Attenuation Control
- Digital Control Of Filter Parameters
- Digitally-Controlled Audio Circuits
- X-Y Graphics
- Digital/Synchro Conversion
- Robotics
- Ideal For Battery-Operated Equipment

CROSS REFERENCE

PMI	ADI	TEMPERATURE RANGE
PM7528AR	AD7528UD	
PM7528BR	AD7528TD	MILITARY
PM7528BR	AD7528SD	
PM7528ER	AD7528CQ	
PM7528FR	AD7528BQ	INDUSTRIAL
PM7528FR	AD7528AQ	
PM7528GP	AD7528LN	
PM7528HP	AD7528KN	
PM7528HP	AD7528JN	COMMERCIAL
PM7528HPC	AD7528KP	
PM7528HPC	AD7528JP	

FUNCTIONAL DIAGRAM



ORDERING INFORMATION[†]

RELATIVE ACCURACY		PACKAGE: 20-PIN				
	GAIN ERROR	MILITARY* TEMPERATURE -55°C TO +125°C	INDUSTRIAL TEMPERATURE -25°C TO +85°C	COMMERCIAL TEMPERATURE 0°C TO +70°C		
±1/2 LSB	±1 LSB	PM7528AR	PM7528ER	PM7528GP		
±1/2 LSB	±1 LSB	PM7528ARC/883	_	_		
±1/2 LSB	±2 LSB	PM7528BR	PM7528FR	PM7528HP		
±1/2 LSB	±2 LSB	PM7528BRC/883	_	PM7528HPC††		
±1/2 LSB	±2 LSB	_	_	PM7528HS††		

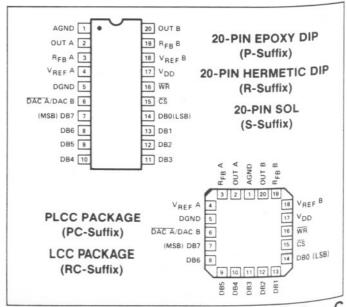
- For devices processed in total compliance to MIL-STD-883, add /883 after part number. Consult factory for 883 data sheet.
- † Burn-in is available on commercial and industrial temperature range parts in cerdip, plastic dip, and TO-can packages. For ordering information, see 1988 Data Book, Section 2.
- †† For availability and burn-in information on SO and PLCC packages, contact your local sales office.

GENERAL DESCRIPTION

The PM-7528 contains two 8-bit multiplying digital-to-analog converters. Excellent DAC-to-DAC matching and tracking results from monolithic construction. The PM-7528 consists of two thin-film R-2R resistor-ladder networks, tracking span resistors, two data latches, one input buffer, and control logic. Operation from a 5 to 15 volt single power supply dissipates only 20mW of power in a space saving 20-pin 0.3" wide DIP. The PM-7528 features circuitry designed to protect against damage from electrostatic discharges.

Digital input data is directed into one of the DAC data latches determined by the DAC selection control line DAC A/DAC B. The 8-bit wide input data path provides TTL/CMOS compatibility. The data load cycle is similar to the write cycle of a random access memory. The PM-7528 is bus compatible with most 8-bit microprocessors, including the 6800, 8080, 8085, and Z80.

PIN CONNECTIONS





ARSOLUTE MAXIMUM RATINGS

TA = +25°C, unless otherwise noted.)
VpD to AGND
to DGND UV, +1/V
IGND to DGND
aidital Input Voltage to DGND0.3V, +15V
V _{PIN 20} to AGND
A, V _{REF} B to AGND ±25V
Vaca A, Vaca B to AGND ±25V
power Dissipation (Any Package) to +75°C 450mW
Derate Above +75°C by 6mW/°C
Operating Temperature Range
AR, ARC, BR, BRC Versions –55°C to +125°C
ER, FR Versions25°C to +85°C
CP HP HPC HS Versions

Dice Junction Temperature	+150°C
Storage Temperature65°C to	+150°C
Lead Temperature (Soldering, 60 sec)	+300°C
CAUTION:	

- Do not apply voltages higher than V_{DD} or less than GND potential on any terminal except V_{REF}.
- The digital control inputs are zener-protected; however, permanent damage
 may occur on unprotected units from high-energy electrostatic fields. Keep
 units in conductive foam at all times until ready to use.
- Do not insert this device into powered sockets; remove power before insertion or removal.
- 4. Use proper anti-static handling procedures.
- Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device.

ELECTRICAL CHARACTERISTICS at $V_{DD}=+5V$ or +15V, V_{REF} A = V_{REF} B = +10V, OUT A = OUT B = 0V; $T_A=-55^{\circ}C$ to $+125^{\circ}C$ apply for PM-7528ER/FR; $T_A=0^{\circ}C$ to $+70^{\circ}C$ apply for PM-7528GP/HP/HPC/HS, unless otherwise noted.

					PM-75	28	
PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
STATIC ACCURACY (Note 1)				, ,			
Resolution	N			8	_	_	Bits
Relative Accuracy (Note 2)	NL		9	_	_	±1/2	LSE
Differential Nonlinearity (Note 3)	DNL		u" "	_	_	±1	LSE
		T _A = +25°C	PM7528A/E/G PM7528B/F/H	_	=	±1 ±2	7
Full Scale Gain Error (Note 4)	G_{FSE}	V _{DD} = +5V T _A = Full Temp. Range	PM7528A/E/G PM7528B/F/H	_	_	±3 ±4	LSE
		V _{DD} = +15V T _A = Full Temp. Range	PM7528A/E/G PM7528B/F/H	_	=	±1 ±3	
Gain Temperature Coefficient (ΔGain/ΔTemperature) (Notes 4, 10)	TCG _{FS}	$V_{DD} = +5V$ $V_{DD} = +15V$	Į.	=	=	±0.007 +0.0035	%/°C
		T _A = +25°C		_	5	±50	
Output Leakage Current Out A (Pin 2)/Out B (Pin 20)	I _{LKG}	V _{DD} = +5V T _A = Full Temp. Range	7	_	_	±400	n.A
(Note 5)		$V_{DD} = +15V$ $T_A = Full Temp. Range$		_	-	+200	
Input Resistance (V _{REF} A, V _{REF} B) (Note 6)	R _{REF}		4	8	_	15	kΩ
V _{REF} A/V _{REF} B (Input Resistance Match)	ΔV _{REF} A, B			-	0.1	±1	%



ELECTRICAL CHARACTERISTICS at $V_{DD}=+5V$ or +15V, V_{REF} A = V_{REF} B = +10V, OUT A = OUT B = 0V; $T_A=-55^{\circ}$ C to $+125^{\circ}$ C apply for PM-7528AR/ARC/BR/BRC; $T_A=-25^{\circ}$ C to $+85^{\circ}$ C apply for PM-7528ER/FR; $T_A=0^{\circ}$ C to $+70^{\circ}$ C apply for PM-7528GP/HP/HPC/HS, unless otherwise noted. (Continued)

				PM-7528			
PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNIT
DIGITAL INPUTS (Note 9)	2		27 · · · · · · · · · · · · · · · · · · ·				
Digital Input High (Note 8)	V _{INH}	$V_{DD} = +5V$ $V_{DD} = +15V$		2.4 13.5	_	_	١
Digital Input Low (Note 8)	V _{INL}	$V_{DD} = +5V$ $V_{DD} = +15V$		=	_	0.8 1.5	\
Input Current (Note 7)	I _{IN}	T _A = +25°C T _A = Full Temp. Range		_	.001	±1 ±10	μА
Input Capacitance (Note 10)	C _{IN}	DB0-DB7 WR, CS, DAC A/DAC B	. *		=	10 15	pF
SWITCHING CHARACTERISTI (Notes 10, 11)	ICS at V _{DD} = +5V	1	8				
Chip Select to Write Set-Up Time	t _{CS}	T _A = +25°C T _A = Full Temp. Range	A 19 7 14 8	200	=	-	ns
Chip Select to Write Hold Time	t _{CH}	T _A = +25°C T _A = Full Temp. Range		20 30	_	_	ns
DAC Select to Write Set-Up Time	t _{AS}	T _A = +25°C T _A = Full Temp. Range		200 230	_	_	ns
DAC Select to Write Hold Time	t _{AH}	T _A = +25°C T _A = Full Temp. Range		20 30	_	_	ns
Data Valid to Write Set-Up Time	t _{DS}	T _A = +25°C T _A = Full Temp. Range		110 130	_	_	ns
Data Valid to Write Hold Time	t _{DH}			0	-	-	ns
Write Pulse Width	t _{WR}	T _A = +25°C T _A = Full Temp. Range		180 200	_	_	ns
SWITCHING CHARACTERISTI (Notes 10, 11)	ICS at V _{DD} = +15V						
Chip Select to Write Set-Up Time	t _{CS}	T _A = +25°C T _A = Full Temp. Range		60 80	_	_	ns
Chip Select to Write Hold Time	t _{CH}	T _A = +25°C T _A = Full Temp. Range		10 15	_	_	ns
DAC Select to Write Set-Up Time	t _{AS}	T _A = +25°C T _A = Full Temp. Range		60 80	_	_	ns
DAC Select to Write Hold Time	t _{AH}	T _A = +25°C T _A = Full Temp. Range		10 15	=	-	ns
Data Valid to Write Set-Up Time	t _{DS}	T _A = +25°C T _A = Full Temp. Range		50 70	_	_	ns
Data Valid to Write Hold Time	t _{DH}			10	_	_	ns
Write Pulse Width	t _{WR}	T _A = +25°C T _A = Full Temp. Range		60 80			ns
		A con comp. riange		00			



ELECTRICAL CHARACTERISTICS at $V_{DD} = +5V$ or +15V, V_{REF} A = V_{REF} B = +10V, OUT A = OUT B = 0V; $T_A = -55^{\circ}C$ to $+125^{\circ}C$ apply for PM-7528AR/ARC/BR/BRC; $T_A = -25^{\circ}C$ to $+85^{\circ}C$ apply for PM-7528ER/FR; $T_A = 0^{\circ}C$ to $+70^{\circ}C$ apply for PM-7528GP/HP/HPC/HS, unless otherwise noted. (Continued)

				PM-7528	3	
ARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
OWER SUPPLY (Note 12)						
Supply Current		All Digital Inputs V _{INL} or V _{INH}	_	-	1	m/
(Note 21)	I _{DD}	All Digital Inputs 0V or V _{DD}	_	_	100	μΑ
C PERFORMANCE CHARACTE (Note 13)	RISTICS					
oc Supply Rejection Ratio		$V_{DD} = +5V$ $T_A = +25$ °C	_	_	0.02	
(ΔGain/ΔV _{DD})	PSRR	T _A = Full Temp. Range	_		0.04	%/9
(Note 14)		$V_{DD} = +15V$			0.01	
		T _A = +25°C T _A = Full Temp. Range	_	_	0.02	
		V _{DD} = +5V				
		T _A = +25°C	_	1 -	220	
propagation Delay	t _{pD}	T _A = Full Temp. Range	_		270	. n
(Notes 15, 16, 17)	рь	$V_{DD} = +15V$			80	
		$T_A = +25$ °C	_	_	80 100	
		T _A = Full Temp. Range			100	
		$V_{DD} = +5V$ $T_A = +25$ °C	_	_	350	
Current Settling Time		$T_A = 723$ G $T_A = \text{Full Temp. Range}$	_	_	400	
(Notes 16, 17, 22)	ts	V _{DD} = +15V				. n
		$T_A = +25$ °C	_	222	180	
		T _A = Full Temp. Range		_	200	
and Oberes Injection		T _A = +25°C				
Digital Charge Injection (Note 18)	Q	$V_{DD} = +5V$	_	160	_	nV
(Hote 19)		$V_{DD} = +15V$		440		
	C _{OUT} A	DAC Latches Loaded	_	_	50	
Output Capacitance	C _{OUT} B	with 00000000			50	- р
Output Gapasitas	C _{OUT} A	DAC Latches Loaded	1.	_	120	
	C _{OUT} B	with 11111111			120	
	-	V _{REF} A to OUT A;			70	
	FTA	$T_A = +25$ °C $T_A = Full Temp. Range$	_	_	-70 -65	
AC Feedthrough		H				_ d
(Note 19)	ET	V _{REF} B to OUT B; T _A = +25°C			-70	
	FTB	$T_A = +25^{\circ}C$ $T_A = \text{Full Temp. Range}$	_		-65	

ELECTRICAL CHARACTERISTICS at V_{DD} = +5V or +15V, V_{REF} A = V_{REF} B = +10V, OUT A = OUT B = 0V; T_A = -55°C to +125°C apply for PM-7528AR/ARC/BR/BRC; TA = -25°C to +85°C apply for PM-7528ER/FR; TA = 0°C to +70°C apply for PM-7528GP/HP/HPC/HS, unless otherwise noted. (Continued)

PARAMETER	SYMBOL	CONDITIONS	MIN	PM-7528		
		CONDITIONS	MIN	ITP	MAX	UNITS
AC PERFORMANCE CHARACTERIST (Note 13)	ics					
Channel-to-Channel	V_{REF} A = 20 V_{p-p} S (CCI_{BA}) @ f = 100kHz V_{REF} B = 0V.	1. The state of th	_	-77	_	
Isolation (Note 20)	CCI _{AB}	V_{REF} B to OUT A; V_{REF} B = 20 V_{p-p} Sinewave @ f = 100kHz V_{REF} A = 0V. T_A = +25°C	** <u>-</u>	-77	-	. dB
Digital Crosstalk	Q	For Code Transition From 00000000 to 11111111. $T_A = +25^{\circ}C$ $V_{DD} = +5V$ $V_{DD} = +15V$	_	30 60	=	nVs
Harmonic Distortion	THD	V _{IN} = 6Vrms @ f = 1kHz. T _A = +25°C	, L	-85	_	dB

NOTES:

- 1. Specifications apply to both DAC A and DAC B.
- 2. This is an endpoint linearity specification.
- 3. All grades guaranteed to be monotonic over the full operating temperature range.
- 4. Measured using internal RFB A and RFB B. Both DAC latches loaded with 11111111. Gain error is adjustable using circuits of Figures 5 and 6.
- DAC loaded with 00000000. 6. Input resistance TC = +50ppm/°C; typical input resistance = 11k Ω .
- V_{IN} = 0V or V_{DD}
- 8. For all data bits DB0-DB7, WR, CS, DAC A/DAC B.
- 9. Logic inputs are MOS gates. Typical input current (+25°C) is less than
- 10. Guaranteed and not tested

- See timing diagram.
- 12. See Figure 3.
- 13. These characteristics are for design guidance only and are not subject to test.
- 14. $\Delta V_{DD} = \pm 5\%$.
- 15. From digital input to 90% of final analog-output current.
- 16. $V_{REF} A = V_{REF} B = +10V$; OUT A, OUT B load = 100Ω , $C_{EXT} = 13pF$.
- 17. \overline{WR} , $\overline{CS} = 0V$, DB0-DB7 = 0V to V_{DD} or V_{DD} to 0V.
- 18. For code transition 00000000 to 11111111.
- 19. $V_{REF} A$, $V_{REF} B = 20V_{p-p}$ Sinewave @ f = 100kHz. 20. Both DAC latches loaded with 11111111.
- 21. $I_{DD} = 500 \mu A$ at $T_A = Full Temp. Range.$
- 22. Extrapolated: $t_s(1/2 LSB) = t_nD + 6.2\tau$, where $\tau =$ the measured first time constant of the final RC decay.